Icemos Technology Ltd Product Specification 1000.277304 Issue Date 18 December 2014 09

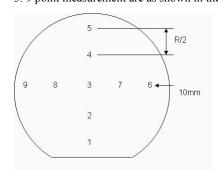
Part Number	Customor	
Part Number	Customer	

Category	Parameter		Specification	Measurement Method
OverallWafer	1.0	Diameter	100.00 +/- 0.20 mm	
	2.0	Primary Flat Orientation	{110}+/-1 degree	Wafer Vendor
	3.0	Primary Flat Length	32.50 +/- 2.50 mm	Wafer Vendor
	4.0	Secondary Flat Orientation	none/semi	
	5.0	Overall Thickness	450.00 +/- 7.00 μm	ADE, 100%
	6.0	Total Thickness Variation (TTV)	<3.00μm	Guaranteed by Process
	7.0	Bow	<80.00μm	ADE to ASTM F534, 20%
	8.0	Warp	<80.00μm	ADE to ASTM F657, 20%
	9.0	Edge Chips	0	Bright Light, 100% (note 2)
	10.0	Edge Exclusion	5mm	
HandleSilicon	11.0	Handle Growth Method	CZ	Wafer Vendor
	12.0	Handle Orientation	{100} +/- 1 degree	Wafer Vendor
	13.0	Handle Thickness	325.00 +/- 5.00 μm	ADE, 100%
	14.0	Handle Doping Type	N	Wafer Vendor
	15.0	Handle Dopant	Phosphorous	Wafer Vendor
	16.0	Handle Resistivity	1-30 Ohmem	Wafer Vendor
	17.0	Backside Finish	Polished with oxide and lasermarking	Guaranteed by Process
BuriedOxide	18.0	Oxide Type	Thermal	
	19.0	Oxide Thickness	10,000.00 +/- 500.00 A	Nanospec centre point, 4%
	20.0	Oxide formed on	Handle Wafer	
DeviceSilicon	21.0	Device Growth Method	FZ	Wafer Vendor
	22.0	Device Orientation	{100} +/- 1 degree	Wafer Vendor
	23.0	Nominal Thickness	124.00 +/- 1.00 μm	FTIR, 100% 9-Pt (note3)
	24.0	Distance to device silicon edge from wafer edge	<= 1.5mm	Typical by Process
	25.0	Device Doping Type	N	Wafer Vendor
	26.0	Device Dopant	Phosphorous	Wafer Vendor
	27.0	Device Resistivity	>2500 Ohmcm	Wafer Vendor
	41.0	Voids	none	Wafer Vendor
	42.0	Scratches	0	Bright Light, 100% (note 2)
	43.0	Haze	none	Bright Light, 100% (note 2)

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Part Number		Customer				
Category	Parameter	Specification		Me	easurement Method	
Shipping Details	Wafer per box :	Max 25				
	Packaging:	Taped Polypropylene Wafer Be Empak, Ultrapak, 100.00mm Antistatic Double Bagging	ox			
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness				
Explanatory Notes	1. Microscope inspec	tion performed using microscope s	can as below. 5x objec	tive.		
		pections performed exclude all was	-		d in Overall	

3. 9 point measurement are as shown in the diagram below:



Additional Information

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